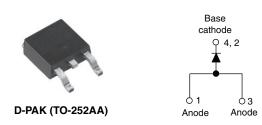
Vishay Semiconductors

High Performance Schottky Rectifier, 10 A



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PRODUCT SUMMARY						
Package	D-PAK (TO-252AA)					
I _{F(AV)}	10 A					
V _R	45 V					
V _F at I _F	0.57 V					
I _{RM}	15 mA at 125 °C					
T _J max.	175 °C					
Diode variation	Single die					
E _{AS}	20 mJ					

FEATURES

- Low forward voltage drop
- Guard ring for enhanced ruggedness and long RoHS compliant reliability
- Popular D-PAK outline
- Small foot print, surface mountable
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-STPS1045B-M3 surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I _{F(AV)}	Rectangular waveform	10	А						
V _{RRM}		45	V						
I _{FSM}	t _p = 5 μs sine	390	А						
V _F	10 A _{pk} , T _J = 125 °C	0.57	V						
TJ	Range	-40 to +175	°C						

VOLTAGE RATINGS									
PARAMETER	VS-STPS1045B-M3	UNITS							
Maximum DC reverse voltage	V _R	45	V						
Maximum working peak reverse voltage	V _{RWM}	40	V						

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST COND	VALUES	UNITS					
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 151 °C	10						
Maximum peak one cycle non-repetitive surge current			Following any rated load condition and with rated	390	А				
See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	V_{RRM} applied	75					
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 \text{ °C}, I_{AS} = 3.0 \text{ A}, L = 4.40$	20	mJ					
Repetitive avalanche current	I _{AR}	Current decaying linearly to zer Frequency limited by T _J maxim	3.0	А					

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ELECTRICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST COND	TEST CONDITIONS						
Maximum forward voltage drop See fig. 1		10 A	T _{.1} = 25 °C	0.63	V				
	V (1)	20 A	1j=23 0	0.84					
	V _{FM} ⁽¹⁾	10 A	T 105 %C	0.57					
		20 A	T _J = 125 °C	0.72					
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C		0.2	mA				
See fig. 2		T _J = 125 °C	V _R = Rated V _R	15					
Typical junction capacitance	CT	$V_R = 5 V_{DC}$ (test signal range	760	pF					
Typical series inductance	L _S	Measured lead to lead 5 mm	5.0	nH					
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs					

Note

⁽¹⁾ Pulse width < 300 μ s, duty cycle < 2 %

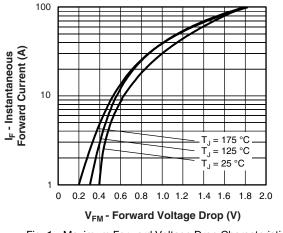
THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER SYMBOL TEST CONDITIONS VA								
Maximum junction and storage temperature range	T_{J} ⁽¹⁾ , T_{Stg}		-40 to +175	°C				
Maximum thermal resistance, junction to case	R _{thJC}	DC operation See fig. 4	3.0	°C/W				
Maximum thermal resistance, junction to ambient	R _{thJA}		50	C/W				
Approximate weight			0.3	g				
			0.01	oz.				
Marking device		Case style D-PAK (similar to TO-252AA)	STPS10	045B				

Note

 $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink (1)

VS-STPS1045B-M3

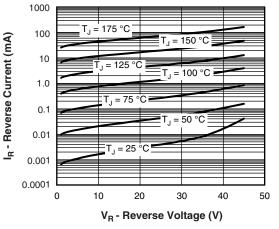
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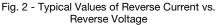


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Fig. 1 - Maximum Forward Voltage Drop Characteristics





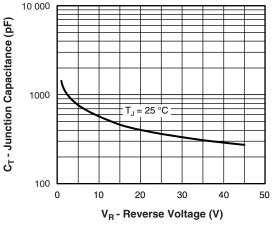


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

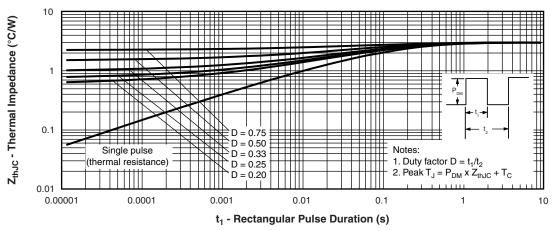


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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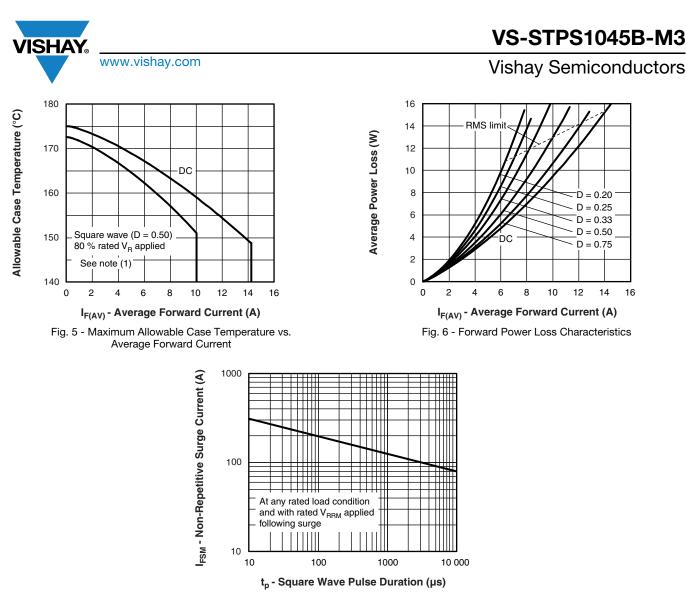


Fig. 7 - Maximum Non-Repetitive Surge Current

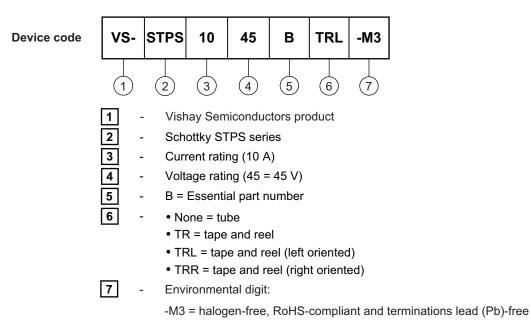
Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $Pd = forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = inverse power loss = V_{R1} \times I_R (1 - D)$; $I_R at V_{R1} = 80 \%$ rated V_R

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ORDERING INFORMATION TABLE



ORDERING INFORMATION (Example)									
PREFERRED P/N	PACKAGING DESCRIPTION								
VS-STPS1045B-M3	75	3000	Antistatic plastic tube						
VS-STPS1045BTR-M3	2000	2000	13" diameter reel						
VS-STPS1045BTRL-M3	3000	3000	13" diameter reel						
VS-STPS1045BTRR-M3	3000	3000	13" diameter reel						

LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?95627					
Part marking information	www.vishay.com/doc?95176					
Packaging information	www.vishay.com/doc?95033					





D-PAK (TO-252AA) "M"

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES	NOTES	SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STNIDUL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	2.18	2.39	0.086	0.094			е	2.29	BSC	0.090	BSC	
A1	-	0.13	-	0.005			Н	9.40	10.41	0.370	0.410	
b	0.64	0.89	0.025	0.035			L	1.40	1.78	0.055	0.070	
b2	0.76	1.14	0.030	0.045			L1	2.74	BSC	0.108	REF.	
b3	4.95	5.46	0.195	0.215	3		L2	0.51	BSC	0.020	BSC	
с	0.46	0.61	0.018	0.024			L3	0.89	1.27	0.035	0.050	3
c2	0.46	0.89	0.018	0.035			L4	-	1.02	-	0.040	
D	5.97	6.22	0.235	0.245	5		L5	1.14	1.52	0.045	0.060	2
D1	5.21	-	0.205	-	3		Ø	0°	10°	0°	10°	
E	6.35	6.73	0.250	0.265	5		Ø1	0°	15°	0°	15°	
E1	4.32	-	0.170	-	3		Ø2	25°	35°	25°	35°	

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Lead dimension uncontrolled in L5

⁽³⁾ Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad

(4) Section C - C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip

(5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

⁽⁶⁾ Dimension b1 and c1 applied to base metal only

⁽⁷⁾ Datum A and B to be determined at datum plane H

⁽⁸⁾ Outline conforms to JEDEC[®] outline TO-252AA



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